

Electronic Information Disclosure Statement

HIGH PERFORMANCE VARACTOR DIODES

3C930 U.S. PRO
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Application: 10/064,754

Confirmation:

Applicant(s): Douglas Coolbaugh

Docket
Number: BUR920020051

Group Art Unit: 2823

Examiner: H. Lee

search string: (3396317 or 3634738 or 3636420 or 3638300 or 3706128 or 3860945 or 4226648 or 4373166 or 4827319).pn.

US Patent Documents

Note: Applicant is not required to submit a paper copy of cited US Patent Documents

Init	Citation No.	Patent Number	Date	Bar Code	Patentee	Class	Subclass
Lee	P01	3396317	1968-08-06		Vendelin	317	234
	P02	3634738	1972-01-11		Leith et al.	317	234
	P03	3636420	1972-01-18		Vendelin	317	234
	P04	3638300	1972-02-01		Foxhall et al.	29	589
	P05	3706128	1972-12-19		Heer	29	578
	P06	3860945	1975-01-14		Dawson	357	14
	P07	4226648	1980-10-07		Goodwin et al.	148	175
	P08	4373166	1983-02-08		Bergeron et al.	357	15
Lee							

<i>Lee</i>	P09	4827319	1989-05-02	Pavlidis et al.	357	14
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Remarks

(Remarks are not for responding to an office action.)

Lee Archambaul et al., Patent No. EP0231700A, Issued 12/19/1986, France Kannam et al., "Design Considerations of Hyperabrupt Varactor Diodes", IEEE Transactions on Electron Devices, Vol. 1, No. 2, 2, February 1971.

Signature

Examiner Name	Date
<i>Kuen Ming Lee</i>	<i>12/24/03</i>